

SCLS394J-APRIL 1999-REVISED FEBRUARY 2015

SNx4LV132A Quadruple Positive-NAND Gates With Schmitt-Trigger Inputs

Technical

Documents

Sample &

Buv

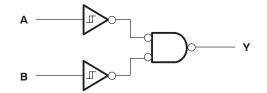
1 Features

- 2-V to 5.5-V V_{CC} Operation
- Max t_{pd} of 9 ns at 5 V
- Typical V_{OLP} (Output Ground Bounce) <0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot) >2.3 V at V_{CC} = 3.3 V, T_A = 25°C
- Support Mixed-Mode Voltage Operation on All Ports
- Latch-Up Performance Exceeds 250 mA per JESD 17
- I_{off} Supports Live Insertion, Partial Power-Down Mode, and Back Drive Protection
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

2 Applications

- Industrial PC: Rugged PC and Laptop
- Access Control and Security: Camera Surveillance IP Network
- Vending, Payment and Change Machines
- Patient Monitoring STB / DVR / Streaming Media (Withdraw)
- Other Motor Drives (Such as Switch Reluctance)

4 Logic Diagram (Positive Logic)



3 Description

Tools &

Software

The 'LV132A devices are quadruple positive-NAND gates designed for 2-V to 5.5-V V_{CC} operation.

Support &

Community

20

The <u>'LV132A</u> devices perform the Boolean function Y = $\overline{A \cdot B}$ or Y = $\overline{A + B}$ in positive logic.

Each circuit functions as a NAND gate, but because of the Schmitt trigger, it has different input threshold levels for positive- and negative-going signals.

These circuits are temperature compensated and can be triggered from the slowest of input ramps and still give clean jitter-free output signals.

PART NUMBER	PACKAGE	BODY SIZE (NOM)					
	SOIC (14)	8.65 mm × 3.91 mm					
	SOP (14)	10.30 mm × 5.30 mm					
LV132A	SSOP (14)	6.20 mm × 5.30 mm					
	TSSOP (14)	5.00 mm × 4.40 mm					
	TVSOP (14)	3.60 mm × 4.40 mm					

Device Information⁽¹⁾

(1) For all available packages, see the orderable addendum at the end of the data sheet.

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5 Revision History

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•	Added ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation	
	section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and	
	Mechanical, Packaging, and Orderable Information section	1

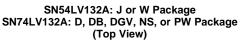


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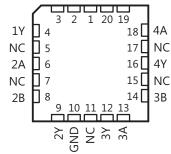


6 Pin Configuration and Functions



1A 1B 1Y 2A 2B 2Y		12 13 12 11 10 9	3	V _{CC} 4B 4A 4A 4Y 3B 3A
2Y 🛛	6	9	- H-	
gnd [7	8	3	3Y

SN54LV132A: FK Package (Top View) 3 2 1 20 19 Π4 5



A. NC - No internal connection

Pin Functions

Р	IN		DECODIDION
NO.	NAME	I/O	DESCRIPTION
1	1A	I	1A input
2	1B	I	1B
3	1Y	0	1Y
4	2A	I	2A
5	2B	I	2B
6	2Y	0	2Y
7	GND	—	GND
8	ЗҮ	0	3Y
9	3A	I	3A
10	3B	I	3В
11	4Y	0	4Y
12	4A	I	4A
13	4B	I	4B
14	V _{CC}		V _{CC}

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7 Specifications

7.1 Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage		-0.5	7	V
VI	Input voltage ⁽²⁾		-0.5	7	V
Vo	Voltage applied to any output in the h	igh-impedance or power-off state ⁽²⁾	-0.5	7	V
Vo	Output voltage ^{(2) (3)}		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-20	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
I _O	Continuous output current	$V_{O} = 0$ to V_{CC}	-25	25	mA
	Continuous current through V _{CC} or GND		-50	50	mA
T _{stg}	Storage temperature		-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The value is limited to 5.5-V maximum.

7.2 ESD Ratings

			VALUE	UNIT
		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000	V
	aloonargo	Machine model (A115-A)	200	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

See (1)(2)

			MIN	MAX	UNIT
V _{CC}	Supply voltage		2	5.5	V
VI	Input voltage			5.5	V
Vo	Output voltage		0	V _{CC}	V
		$V_{CC} = 2 V$		-50	μA
I _{OH}	High lovel output ourrent	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		-2	
	High-level output current	$V_{CC} = 3 V$ to 3.6 V		-6	mA
		V_{CC} = 4.5 V to 5.5 V		-12	
		$V_{CC} = 2 V$		50	μA
	Low lovel output ourrent	V_{CC} = 2.3 V to 2.7 V		2	
I _{OL}	Low-level output current	$V_{CC} = 3 V$ to 3.6 V		6	mA
		V_{CC} = 4.5 V to 5.5 V		12	
-	T _A Operating free-air temperature	SN54LV132A	-55	125	°C
IA		SN74LV132A	-40	125	

 All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See the TI application report, Implications of Slow or Floating CMOS Inputs, SCBA004.

(2) SN54LV132A is in product preview



7.4 Thermal Information

over operating free-air temperature range (unless otherwise noted)

		D	DB	DGV	NS	PW	
			14 PINS				
$R_{\theta JA}$	Junction-to-ambient thermal resistance	90.6	107.1	129.0	90.7	122.6	
R _{0JC(top)}	Junction-to-case (top) thermal resistance	50.9	59.6	52.1	48.3	51.4	
$R_{\theta J B}$	Junction-to-board thermal resistance	44.8	54.4	62.0	49.4	64.4	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	14.7	20.5	6.5	14.6	6.7	
Ψ_{JB}	Junction-to-board characterization parameter	44.5	53.8	61.3	49.1	63.8	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

7.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

				SN54L	.V132A ⁽¹⁾	SN74		
	PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP MAX	MIN	TYP MAX	UNIT
			2.5 V	1	1.75	1	1.75	
V_{T+}	Positive-going input threshold voltage		3.3 V	1.31	2.31	1.31	2.31	V
	threahold voltage		5 V	1.95	3.5	1.95	3.5	
			2.5 V	0.75	1.5	0.75	1.5	
V_{T-}	Negative-going input threshold voltage		3.3 V	0.99	2.07	0.99	2.07	V
	anoonola voltago		5 V	1.5	3.05	1.5	3.05	
			2.5 V	0.25	1	0.25	1	
$\Delta V_{\rm T}$	Hysteresis (V _{T+} – V _{T-})		3.3 V	0.33	1.32	0.33	1.32	V
	(v + v -)		5 V	0.5	2	0.5	2	
		I _{OH} = -50 μA	2 to 5.5 V	V _{CC} – 0.1		V _{CC} – 0.1		
V		$I_{OH} = -2 \text{ mA}$	2.3 V	2		2		v
V _{OH}		I _{OH} = -6 mA	3 V	2.48		2.48		v
		$I_{OH} = -12 \text{ mA}$	4.5 V	3.8		3.8		
		$I_{OL} = 50 \ \mu A$	2 to 5.5 V		0.1		0.1	
V		$I_{OL} = 2 \text{ mA}$	2.3 V		0.4		0.4	V
V _{OL}		$I_{OL} = 6 \text{ mA}$	3 V		0.44		0.44	v
		I _{OL} = 12 mA	4.5 V		0.55		0.55	
կ		$V_I = 5.5 V \text{ or GND}$	0 to 5.5 V		±1		±1	μA
I _{CC}		$V_{I} = V_{CC} \text{ or GND, } I_{O}$ = 0	5.5 V		20		20	μA
I _{off}		V_{I} or V_{O} = 0 to 5.5 V	0 V		5		5	μA
Ci		$V_I = V_{CC}$ or GND	3.3 V		1.9		1.9	pF

(1) SN54LV132A is in product preview

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7.6 Switching Characteristics

over recommended operating free-air temperature range, V_{CC} = 2.5 V ±0.2 V (unless otherwise noted) (see Figure 3)

	DADAMETER			LOAD	т	_A = 25°C		SN54LV	132A ⁽¹⁾	SN74LV	/132A	UNIT
PARAMETER	FROM (INPUT)	TO (OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT	
		A or D	V	C _L = 15 pF		7.9 ⁽²⁾	16.5 ⁽²⁾	1 ⁽²⁾	18.5 ⁽²⁾	1	18.5	22
	^L pd	A or B	T	C _L = 50 pF		10.8	20.2	1	23	1	23	ns

(1) SN54LV132A is in product preview

(2) On products compliant to MIL-PRF-38535, this parameter is not production tested.

7.7 Switching Characteristics

over recommended operating free-air temperature range, V_{CC} = 3.3 V ±0.3 V (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)		LOAD	т	_A = 25°C		SN54LV1	132A ⁽¹⁾	SN74LV	132A	UNIT
		TO (OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
	A or P	V	C _L = 15 pF		5.6 ⁽²⁾	11.9 ⁽²⁾	1 ⁽²⁾	14 ⁽²⁾	1	14	20
^L pd	t _{pd} A or B	Y	C _L = 50 pF		7.6	15.4	1	17.5	1	17.5	ns

(1) SN54LV132A is in product preview

(2) On products compliant to MIL-PRF-38535, this parameter is not production tested.

7.8 Switching Characteristics

over recommended operating free-air temperature range, $V_{CC} = 5 V \pm 0.5 V$ (unless otherwise noted) (see Figure 3)

PARAMETER	FROM	то	LOAD	T,	_A = 25°C		SN54LV1	132A ⁽¹⁾	SN74LV	/132A	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
t _{pd} A or B	A or P	V	C _L = 15 pF		3.9 ⁽²⁾	7.7 ⁽²⁾	1 (2)	9(2)	1	9	20
	AUB	ř	C _L = 50 pF		5.3	9.7	1	11	1	11	ns

(1) SN54LV132A is in product preview

(2) On products compliant to MIL-PRF-38535, this parameter is not production tested.

7.9 Noise Characteristics for SN74LV132A

 V_{CC} = 3.3 V, C_L = 50 pF, T_A = 25°C⁽¹⁾

	PARAMETER	MIN	TYP	MAX	UNIT
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.21	0.8	
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.09	-0.8	
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		3.12		V
V _{IH(D)}	High-level dynamic input voltage	2.31			
V _{IL(D)}	Low-level dynamic input voltage			0.99	

(1) Characteristics are for surface-mount packages only.

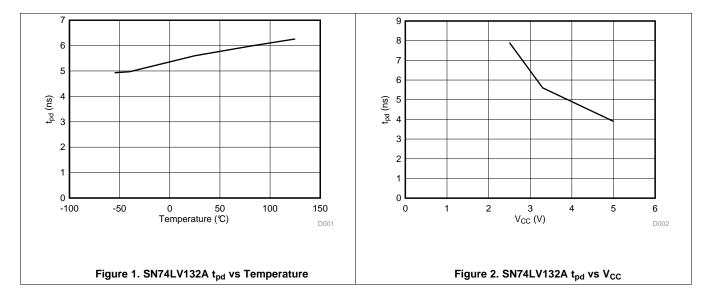
7.10 Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	Vcc	TYP	UNIT
<u> </u>	Dawar dissinction consoltance		3.3 V	7.5	~ [
C _{pd}	Power dissipation capacitance	C _L = 50 pF, f = 10 MHz	5 V	11.2	p⊦



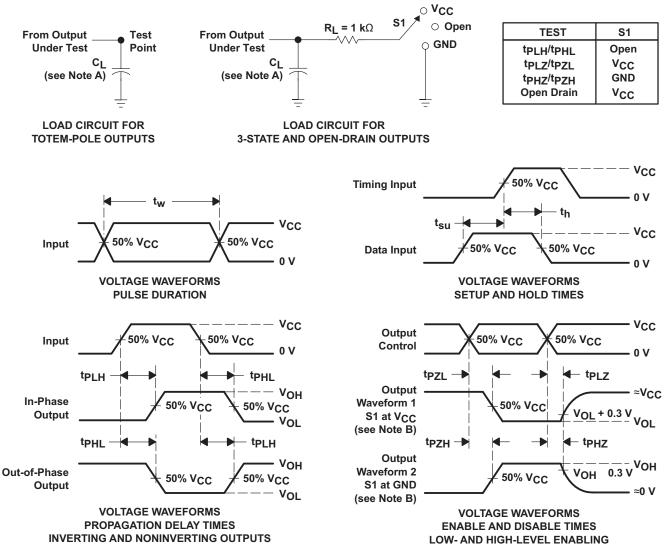
7.11 Typical Characteristics



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8 Parameter Measurement Information



- A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_r \leq 3 ns, t_f \leq 3 ns.
- D. The outputs are measured one at a time, with one input transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and tPZH are the same as t_{en}.
- G. t_{PHL} and t_{PLH} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms

8



9 Detailed Description

9.1 Overview

The SN74LV132A Is a quadruple 2-input positive NAND gate with low drive that produces slow rise and fall times. This reduces ringing on the output signal. Each circuit functions as a NAND gate, but because of the Schmitt trigger, it has different input threshold levels for positive- and negative-going signals. These circuits are temperature compensated and can be triggered from the slowest of input ramps and still give clean jitter-free output signals.

9.2 Functional Block Diagram

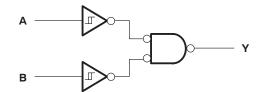


Figure 4. Logic Diagram (Positive Logic)

9.3 Feature Description

- Wide operating voltage range, operates from 2 to 5.5 V
- Allows down voltage translation, inputs accept voltages to 5.5 V

9.4 Device Functional Modes

Table 1. Function Table

INP	OUTPUT					
Α	A B					
Н	Н	L				
L	Х	Н				
Х	L	Н				

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10 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

The SN74LV132A is a low-drive CMOS device that can be used for a multitude of bus interface type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The inputs can accept voltages to 5.5 V at any valid V_{CC} making it Ideal for down translation.

10.2 Typical Application

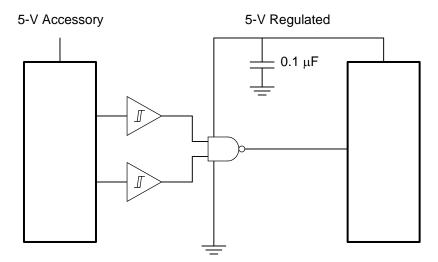


Figure 5. Typical Application Schematic

10.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing. The Schmitt trigger inputs allow for slow or noisy inputs while producing clean outputs.

10.2.2 Detailed Design Procedure

- 1. Recommended input conditions
 - Specified high and low levels. See (V_{IH} and V_{IL}) in *Recommended Operating Conditions*.
 - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V_{CC}
- 2. Recommend output conditions
 - Load currents should not exceed 25 mA per output and 50 mA total for the part
 - Outputs should not be pulled above V_{CC}



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Typical Application (continued)

10.2.3 Application Curve

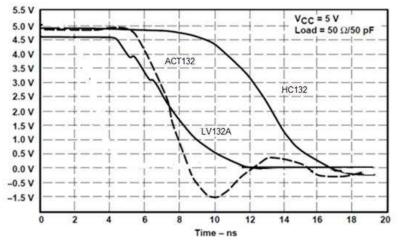


Figure 6. Switching Characteristics Comparison

11 Power Supply Recommendations

The power supply can be any voltage between the min and max supply voltage rating located in *Recommended Operating Conditions*.

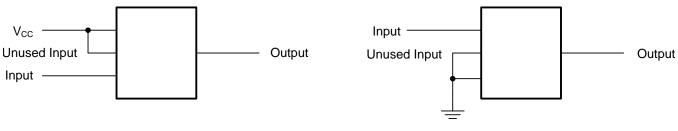
Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, TI recommends 0.1 μ F and if there are multiple V_{CC} terminals then TI recommends .01 μ F or .022 μ F for each power terminal. It is okay to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 μ F and 1 μ F are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

12 Layout

12.1 Layout Guidelines

When using multiple bit logic devices inputs should not ever float. In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified below are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} whichever make more sense or is more convenient. It is generally okay to float outputs unless the part is a transceiver. If the transceiver has an output enable pin it will disable the outputs section of the part when asserted. This will not disable the input section of the IOs so they also cannot float when disabled.

12.2 Layout Example





13 Device and Documentation Support

13.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

PARTS	PRODUCT FOLDER	PRODUCT FOLDER SAMPLE & BUY TECHI DOCUM		TOOLS & SOFTWARE	SUPPORT & COMMUNITY	
SN54LV132A	Click here	Click here	Click here	Click here	Click here	
SN74LV132A	Click here	Click here	Click here	Click here	Click here	

Table 2. Related Links

13.2 Trademarks

All trademarks are the property of their respective owners.

13.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable Device	Status	Package Type		Pins		Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN74LV132AD	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV132A	Samples
SN74LV132ADBR	ACTIVE	SSOP	DB	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV132A	Samples
SN74LV132ADGVF	ACTIVE	TVSOP	DGV	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV132A	Samples
SN74LV132ADR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV132A	Samples
SN74LV132ADRE4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV132A	Samples
SN74LV132ANSR	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	74LV132A	Samples
SN74LV132APW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV132A	Samples
SN74LV132APWE4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV132A	Samples
SN74LV132APWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV132A	Samples
SN74LV132APWRG	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV132A	Samples
SN74LV132APWT	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV132A	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ **RoHS**: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.



24-Aug-2018

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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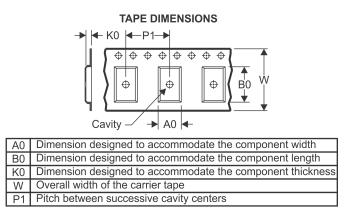
PACKAGE MATERIALS INFORMATION

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Texas Instruments

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV132ADGVR	TVSOP	DGV	14	2000	330.0	12.4	6.8	4.0	1.6	8.0	12.0	Q1
SN74LV132ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LV132ANSR	SO	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74LV132APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV132APWT	TSSOP	PW	14	250	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

20-Dec-2018



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV132ADGVR	TVSOP	DGV	14	2000	367.0	367.0	35.0
SN74LV132ADR	SOIC	D	14	2500	367.0	367.0	38.0
SN74LV132ANSR	SO	NS	14	2000	367.0	367.0	38.0
SN74LV132APWR	TSSOP	PW	14	2000	367.0	367.0	35.0
SN74LV132APWT	TSSOP	PW	14	250	367.0	367.0	35.0

MECHANICAL DATA

PLASTIC SMALL-OUTLINE PACKAGE

0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 \bigcirc Gage Plane ₽ 0,25 7 1 1,05 0,55 0-10 Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS ** 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G**)

14-PINS SHOWN

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



MECHANICAL DATA

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

DGV (R-PDSO-G**)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

14/16/20/56 Pins – MO-194



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



A. An integration of the information o

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



MECHANICAL DATA

MSSO002E - JANUARY 1995 - REVISED DECEMBER 2001

DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-150



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